

#### **FEATURES**

- Low Supply Current...20 μA Typ
- Single Power Supply
- Rail-to-Rail Common-Mode Input Voltage Range
- Push-Pull Output Circuit
- Low Input-Bias Current

#### **APPLICATIONS**

- · Battery Packs for Sensing Battery Voltage
- MP3 Players, Digital Cameras, PMPs
- Cellular Phones, PDAs, Notebook Computers
- Test Equipment
- General-Purpose Low-Voltage Applications

#### **DESCRIPTION/ORDERING INFORMATION**

The TLV7256 is a CMOS-type general-purpose dual comparator capable of single power-supply operation and using lower supply currents than the conventional bipolar comparators. Its push-pull output can connect directly to local ICs such as TTL and CMOS circuits.

#### ORDERING INFORMATION(1)

T <sub>A</sub>	PACKAGE <sup>()</sup>		ORDERABLE PART NUMBER	TOP-SIDE MARKING
	SSOP - DCT	Reel of 3000	TLV7256IDCTR	PREVIEW
-40°C to 85°C	330P - DC1	Reel of 250	TLV7256IDCTT	PREVIEW
	VSSOP - DDU	Reel of 3000	TLV7256IDDUR	YAUA

- (1) For the most current package and ordering information, see the Package Option Addendum at the end of this document, or see the TI web site at www.ti.com.
- (2) Package drawings, standard packing quantities, thermal data, symbolization, and PCB design guidelines are available at www.ti.com/sc/package.

#### **Typical Application Circuit**

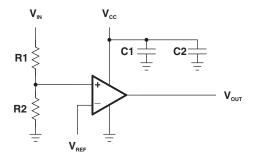
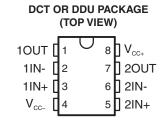


Figure 1. Threshold Detector



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.



## TLV7256 DUAL COMPARATOR





# Absolute Maximum Ratings<sup>(1)</sup>

over operating free-air temperature range (unless otherwise noted)

				MIN	MAX	UNIT
V <sub>CC</sub>	Supply voltage	Supply voltage				V
$V_{ID}$	Differential input voltage					V
VI	Input voltage			V <sub>CC</sub> -	V <sub>CC+</sub>	V
Io	Output current				±35	mA
0	Thermal resistance, juction to ambient <sup>(2)</sup>	DCT package			220	°C/W
$\theta_{JA}$	Thermal resistance, juction to ambients	DDU package			227	C/VV
D	Dower discination	DCT package			250	\//
$P_D$	Power dissipation	DDU package			200	mW
T <sub>A</sub>	Operating free-air temperature range			-40	85	°C
T <sub>stg</sub>	Storage temperature range			<b>-</b> 55	125	°C

<sup>(1)</sup> Stresses beyond those listed under absolute maximum ratings may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under recommended operating conditions is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

#### **Recommended Operating Conditions**

		MIN	MAX	UNIT
$V_{CC}$	Supply voltage	1.8	5	V
T <sub>A</sub>	Operating free-air temperature	-40	85	°C

<sup>(2)</sup> Package thermal impedance is calculated according to JESD 51-7.



# **Electrical Characteristics**

 $V_{CC+}$  = 5 V,  $V_{CC-}$  = GND,  $T_A$  = 25°C (unless otherwise noted)

	PARAMETER	TEST CONDITIONS	T <sub>A</sub>	MIN	TYP	MAX	UNIT
V	lanut offeet voltege		25°C		±2	±7	mV
$V_{IO}$	Input offset voltage		–40°C to 85°C			±8	mv
I <sub>IO</sub>	Input offset current		25°C		2		рА
I <sub>I</sub>	Input bias current		25°C		4		pА
$V_{CM}$	Common-mode input voltage		25°C	0		V <sub>CC</sub>	V
CMRR	Common mode valenties votice	$\Delta V_{CM} = 5 V$	25°C	48	65		dB
CIVIKK	Common-mode rejection ratio	0 ≤ V <sub>CM</sub> ≤ 5 V	–40°C to 85°C	48			uБ
		Output = High, V <sub>IN</sub> = 5 V	25°C		37	51	
	Supply current	Output = Low, $V_{IN} = 5 \text{ V}$	25°C		40	60	μΑ
		Output = High, $V_{IN} = 5 \text{ V}$	-40°C to 85°C			61	
		Output = Low, $V_{IN} = 5 \text{ V}$	-40 C t0 65 C			70	
I <sub>CC</sub>		Output = High, V <sub>IN</sub> = 2.5 V	25°C		20	32	
		Output = Low, $V_{IN} = 2.5 \text{ V}$	25 C		26	42	
		Output = High, $V_{IN} = 2.5 \text{ V}$	-40°C to 85°C			40	
		Output = Low, $V_{IN} = 2.5 \text{ V}$	-40 C t0 65 C			53	
$A_{VD}$	Voltage gain	$V_D = 3 \text{ V}, 1 \text{ V} \leq V_{OUT} \leq 4 \text{ V}$	25°C		88		dB
	Cink current	V 05.V	25°C	25	33		mA
I <sub>sink</sub>	Sink current	$V_{OL} = 0.5 \text{ V}$	–40°C to 85°C	20			
	Course current	V 45V	25°C	30	35		<b>~</b> ∧
source	Source current	V <sub>OH</sub> = 4.5 V	-40°C to 85°C	25			mA
.,	Low lovel output voltage	I 5 m A	25°C		0.07	0.12	V
$V_{OL}$	Low-level output voltage	$I_{sink} = 5 \text{ mA}$	–40°C to 85°C			0.20	V
V	High level cutout voltege	Ι <i>Ε</i> το Δ	25°C	4.9	4.93		V
$V_{OH}$	High-level output voltage	I <sub>source</sub> = 5 mA	-40°C to 85°C	4.85			V



#### **Electrical Characteristics**

 $V_{CC+}$  = 2.7 V,  $V_{CC-}$  = GND,  $T_A$  = 25°C (unless otherwise noted)

	PARAMETER	TEST CONDITIONS	T <sub>A</sub>	MIN	TYP	MAX	UNIT
V	long to offer the veltage		25°C		±2	±8	mV
$V_{IO}$	Input offset voltage		-40°C to 85°C			±9	mv
I <sub>IO</sub>	Input offset current		25°C		2		рА
I <sub>I</sub>	Input bias current		25°C		4		рА
$V_{CM}$	Common-mode input voltage		25°C	0		V <sub>CC</sub>	V
CMRR	Common mode rejection ratio	$\Delta V_{CM} = 2.7 \text{ V}$	25°C	42	57		dB
CIVIKK	Common-mode rejection ratio	$0 \le V_{CM} \le 2.7 \text{ V}$	-40°C to 85°C	42			uБ
		Output = High, V <sub>IN</sub> = 2.7 V	25°C		30	55	
		Output = Low, $V_{IN} = 2.7 \text{ V}$	25 C		36	55	μΑ
	Supply current	Output = High, $V_{IN} = 2.7 \text{ V}$	-40°C to 85°C			65	
		Output = Low, $V_{IN} = 2.7 \text{ V}$	-40 C to 65 C			65	
I <sub>CC</sub>		Output = High, V <sub>IN</sub> = 1.35 V	25°C		30	48	
		Output = Low, $V_{IN} = 1.35 \text{ V}$	25 C		35	55	
		Output = High, V <sub>IN</sub> = 1.35 V	-40°C to 85°C			55	
		Output = Low, $V_{IN} = 1.35 \text{ V}$	-40 C to 65 C			65	
$A_{VD}$	Voltage gain	$V_D = 1.7 \text{ V}, \ 0.5 \text{ V} \le V_{OUT} \le 2.2 \text{ V}$	25°C		88		dB
_	Sink current	V - 0.5 V	25°C	13	18		mA
I <sub>sink</sub>	Sink current	V <sub>OL</sub> = 0.5 V	–40°C to 85°C	11			ША
-	Course current	V 22V	25°C	15	20		A
source	Source current	$V_{OH} = 2.2 \text{ V}$	-40°C to 85°C	13			mA
V	Low lovel output voltage	I 5 m A	25°C		0.11	0.16	V
$V_{OL}$	Low-level output voltage	$I_{sink} = 5 \text{ mA}$	–40°C to 85°C			0.19	V
V	High level output voltage	1 - 5 mA	25°C	2.54	2.60		V
V <sub>OH</sub>	High-level output voltage	I <sub>source</sub> = 5 mA	-40°C to 85°C	2.45			V



# **Electrical Characteristics**

 $V_{CC+}$  = 1.8 V,  $V_{CC-}$  = GND,  $T_A$  = 25°C (unless otherwise noted)

	PARAMETER	TEST CONDITIONS	T <sub>A</sub>	MIN	TYP	MAX	UNIT
.,	lanut offeet voltage		25°C		±2	±8	mV
V <sub>IO</sub>	Input offset voltage		-40°C to 85°C			±9	mv
I <sub>IO</sub>	Input offset current		25°C		2		рА
I	Input bias current		25°C		4		рА
$V_{CM}$	Common-mode input voltage		25°C	0		$V_{CC} - 0.3$	V
CMRR	Common-mode rejection ratio	$\Delta V_{CM} = 5 \text{ V}$	25°C	40	55		dB
CIVIKK	Common-mode rejection ratio	$0 \le V_{CM} \le 5 V$	–40°C to 85°C	40			uБ
		Output = High, V <sub>IN</sub> = 1.8 V	25°C		30	55	
		Output = Low, V <sub>IN</sub> = 1.8 V	25 C		33	47	μΑ
	Supply current	Output = High, $V_{IN} = 1.8 \text{ V}$	–40°C to 85°C			60	
		Output = Low, $V_{IN} = 1.8 \text{ V}$	-40 C to 65 C			51	
I <sub>CC</sub>		Output = High, $V_{IN} = 0.9 \text{ V}$	25°C		20	32	
		Output = Low, $V_{IN} = 0.9 V$	25 C		25	37	
		Output = High, $V_{IN} = 0.9 \text{ V}$	-40°C to 85°C			34	
		Output = Low, $V_{IN} = 0.9 V$	40 0 10 00 0	40			
$A_{VD}$	Voltage gain	$V_D = 1.1 \text{ V}, 0.4 \text{ V} \le V_{OUT} \le 1.5 \text{ V}$	25°C		88		dB
	Sink current	V 05V	25°C	6	9		mA
Isink	Sink current	V <sub>OL</sub> = 0.5 V	–40°C to 85°C	5			ША
	Source current	V <sub>OH</sub> = 2.2 V	25°C	5	9		mA
Isource	Source current	V <sub>OH</sub> = 2.2 V	–40°C to 85°C	4			ША
	Low level output voltage	Ι – 5 mΛ	25°C		0.2	0.34	V
V <sub>OL</sub>	Low-level output voltage	I <sub>sink</sub> = 5 mA	-40°C to 85°C			0.39	V
V	High-level output voltage		25°C	1.3	1.6		V
V <sub>OH</sub>	i ligh-level output voltage	I <sub>source</sub> = 5 mA	-40°C to 85°C	1.2			V

## TLV7256 DUAL COMPARATOR

SLCS147A-OCTOBER 2006-REVISED JANUARY 2007



#### **Switching Characteristics**

 $V_{CC+}$  = 5 V,  $V_{CC-}$  = GND,  $T_A$  = 25°C (unless otherwise noted)

	PARAMETER	TEST CONDITIONS	TYP	UNIT
	Drangation dolay time (turn on)	Overdrive = 100 mV	680	20
t <sub>PLH</sub> Propagation delay time (turn on)		TTL step input	500	ns
	Dranagation delay time (turn off)	Overdrive = 100 mV	250	
t <sub>PHL</sub>	Propagation delay time (turn off)	TTL step input	380	ns
t <sub>TLH</sub>	Response time	Overdrive = 100 mV	60	no
t <sub>THL</sub>	Response time	Overdrive = 100 mv	8	ns

# **Switching Characteristics**

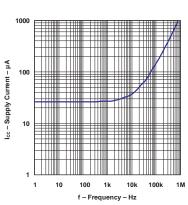
 $V_{CC+} = 3 \text{ V}, V_{CC-} = \text{GND}, T_A = 25^{\circ}\text{C} \text{ (unless otherwise noted)}$ 

	PARAMETER	TEST CONDITIONS	TYP	UNIT
t <sub>PLH</sub>	Propagation delay time (turn on)	Overdrive = 100 mV	550	ns
t <sub>PHL</sub>	Propagation delay time (turn off)	Overdrive = 100 mV	250	ns
t <sub>TLH</sub>	Door once time	Output the 100 ml/	30	
t <sub>THL</sub>	Response time	Overdrive = 100 mV	8	ns

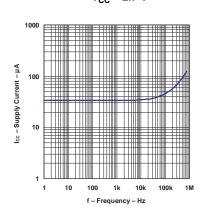


#### TYPICAL CHARACTERISTICS

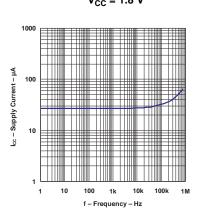
SUPPLY CURRENT
vs
FREQUENCY
V<sub>CC</sub> = 5 V



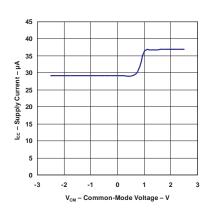
SUPPLY CURRENT
VS
FREQUENCY
V<sub>CC</sub> = 2.7 V



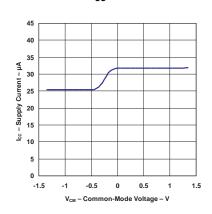
SUPPLY CURRENT
VS
FREQUENCY
V<sub>CC</sub> = 1.8 V



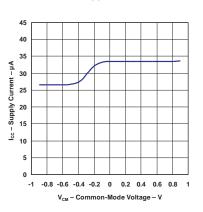
SUPPLY CURRENT vs COMMON-MODE VOLTAGE  $V_{CC} = \pm 2.5 \text{ V}$ 



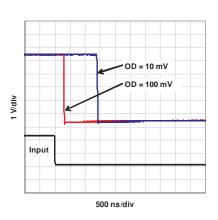
SUPPLY CURRENT VS COMMON-MODE VOLTAGE VCC =  $\pm 1.35$  V



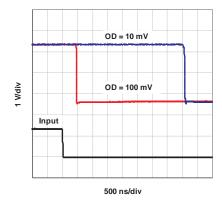
SUPPLY CURRENT vs COMMON-MODE VOLTAGE V<sub>CC</sub> =  $\pm 0.9$  V



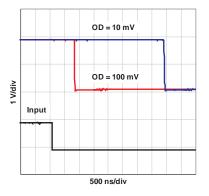
PROPAGATION DELAY TIME, HIGH TO LOW  $V_{CC} = 5 \ V$ 



PROPAGATION DELAY TIME, HIGH TO LOW V<sub>CC</sub> = 2.7 V

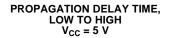


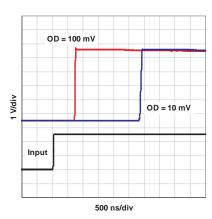
PROPAGATION DELAY TIME, HIGH TO LOW  $V_{CC} = 1.8 \text{ V}$ 



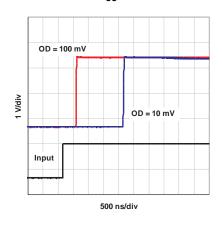


#### **TYPICAL CHARACTERISTICS (continued)**

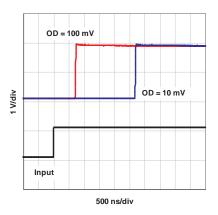




# PROPAGATION DELAY TIME, LOW TO HIGH $V_{CC} = 2.7 \text{ V}$



#### PROPAGATION DELAY TIME, LOW TO HIGH V<sub>CC</sub> = 1.8 V





#### PACKAGE OPTION ADDENDUM

21-Mar-2007

#### **PACKAGING INFORMATION**

Orderable Device	Status <sup>(1)</sup>	Package Type	Package Drawing	Pins P	ackage Qty	e Eco Plan <sup>(2)</sup>	Lead/Ball Finish	MSL Peak Temp <sup>(3)</sup>
TLV7256IDDUR	ACTIVE	VSSOP	DDU	8	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TLV7256IDDURG4	ACTIVE	VSSOP	DDU	8	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

**NRND**: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

**Pb-Free** (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

**Pb-Free (RoHS Exempt):** This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

**Green (RoHS & no Sb/Br):** TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

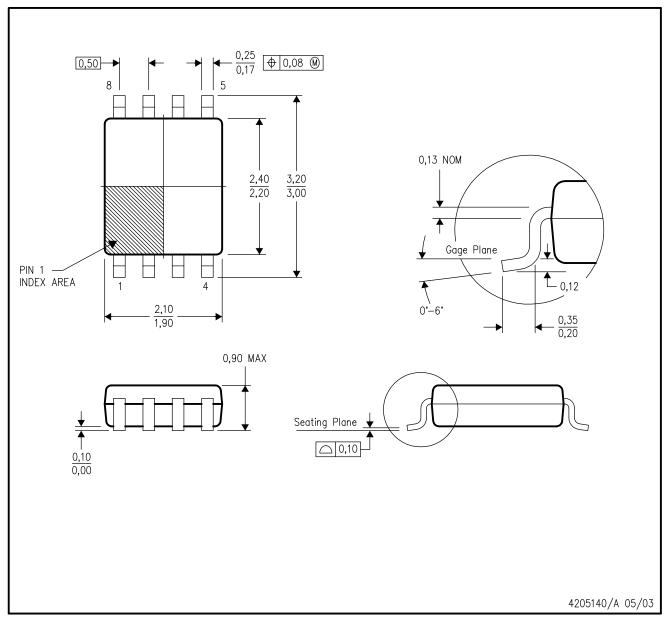
(3) MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

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# DDU (R-PDSO-G8)

# PLASTIC SMALL-OUTLINE PACKAGE



NOTES:

- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion.
- D. Falls within JEDEC MO-187 variation CA.



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